

# Multi-Spectral Infrared Sensing Microsystems

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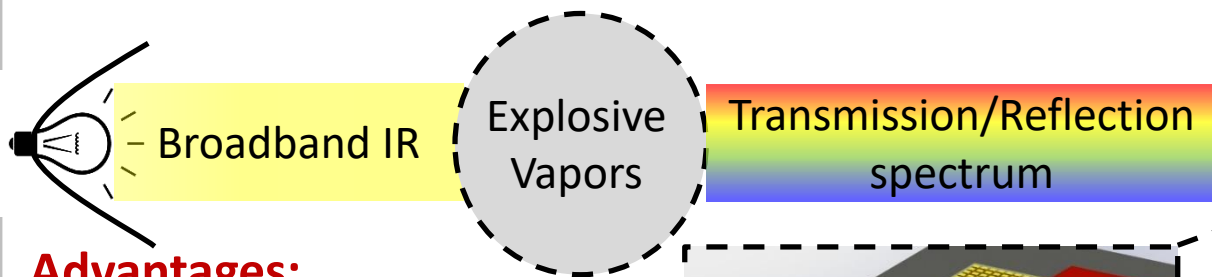
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10/18/2017



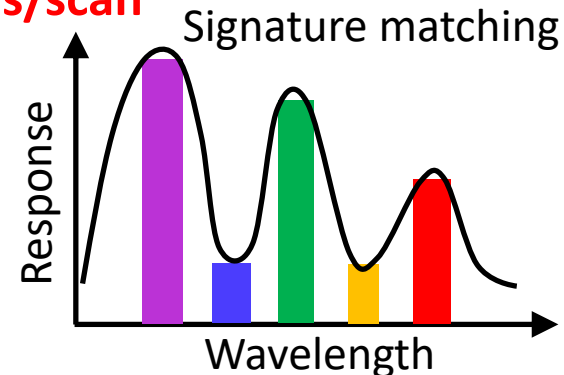
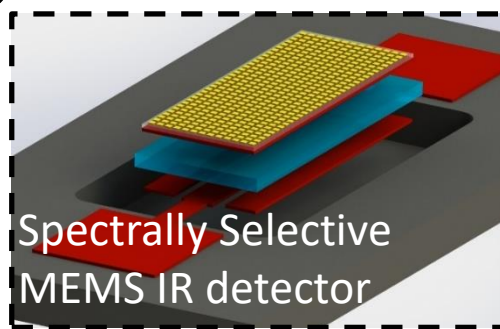
# Uncooled Spectrally Selective IR Detectors for Fast Screening of Explosive Vapors

Multiple detectors acquiring data simultaneously: **< 10 ms/scan**



## Advantages:

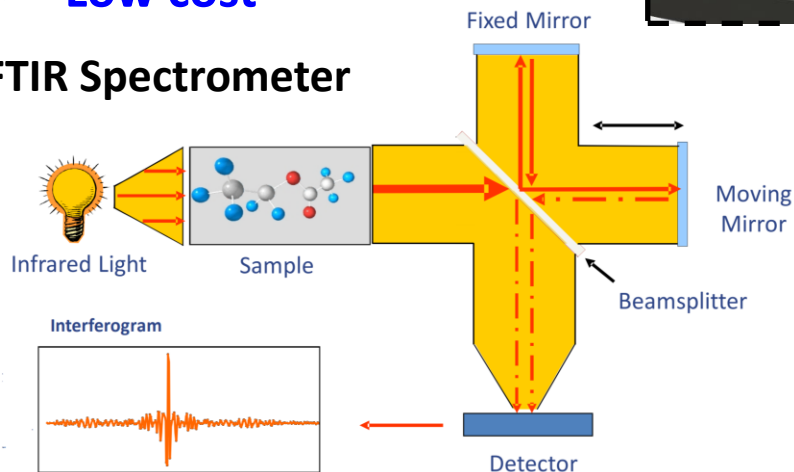
- ✓ Fast data acquisition
- ✓ Low power consumption
- ✓ Small form factor
- ✓ Low cost



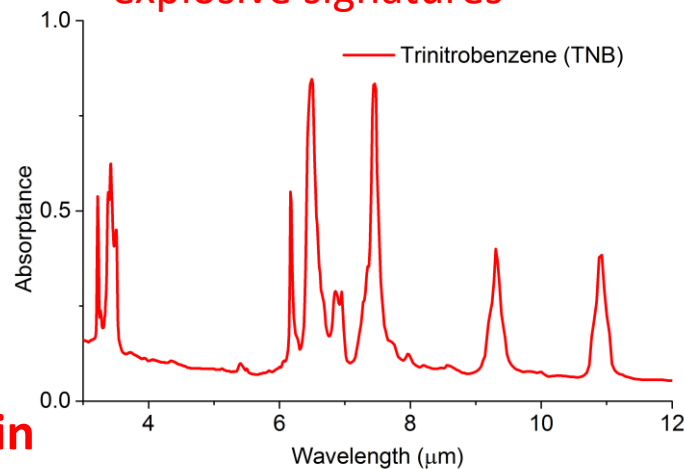
Further measurement with QCL to get high-resolution data if initial scan matches any explosive signatures



## FTIR Spectrometer


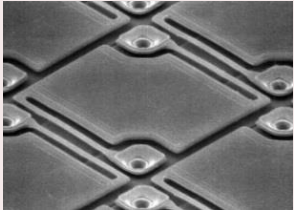


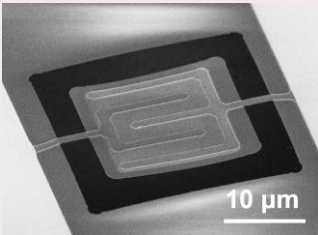


- high-spectral resolution
- wide spectral range
- slow speed
- hard to miniaturize



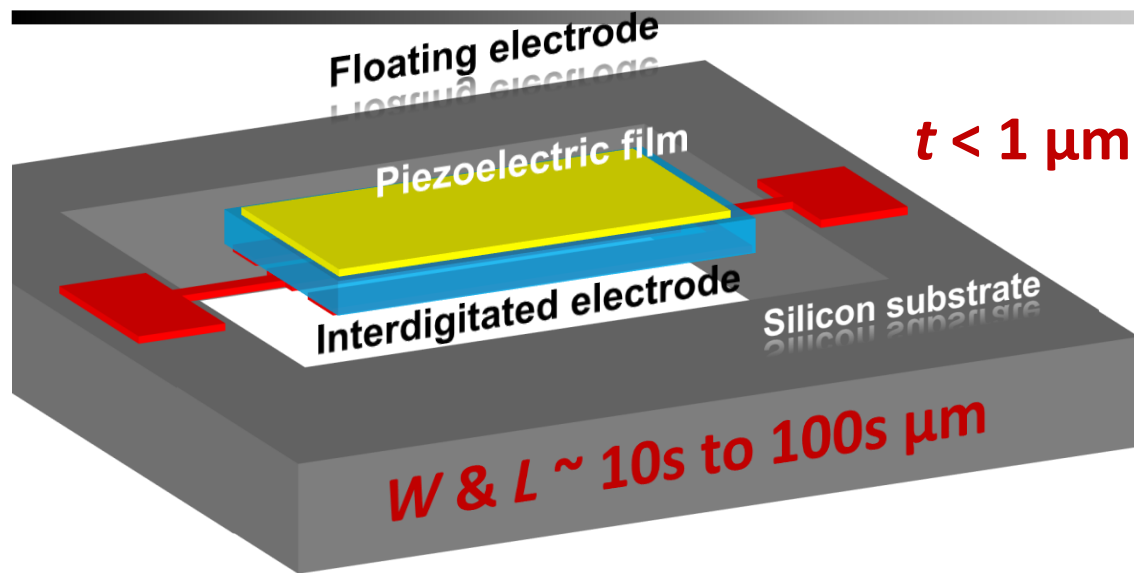
**Time per scan: ~ few seconds to 1 min**

# State-of-the-art IR detector technologies

	Photon Detector	Thermal Detector (uncooled)			
	Cooled	Thermoresistive	Pyroelectric	Thermoelectric	MEMS resonant
Example	 HgCdTe(MCT) / Quantum well	 Microbolometer	 PIR sensor	 Thermopile	 AlN Nano Plate Resonator
NEP	$< \text{pW}/\text{Hz}^{1/2}$	$\sim 100\text{s pW}/\text{Hz}^{1/2}$	$\sim 100\text{s pW}/\text{Hz}^{1/2}$	$\sim \text{nW}/\text{Hz}^{1/2}$	$\sim 10\text{s pW}/\text{Hz}^{1/2}$
Speed	ps - $\mu\text{s}$	10s ms	10s ms	10s ms	$\sim 10\text{s } \mu\text{s}$
Pixel Size	$30 \times 30 \mu\text{m}^2$	$25 \times 25 \mu\text{m}^2$	$40 \times 40 \mu\text{m}^2$	$200 \times 200 \mu\text{m}^2$	$\sim 30 \times 30 \mu\text{m}^2$
Selectivity	Broad/Narrow	Broadband	Broadband	Broadband	<b>Narrowband</b>

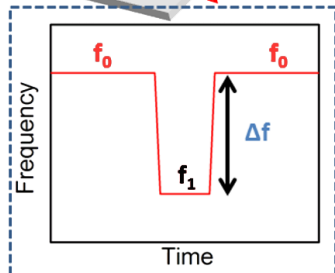
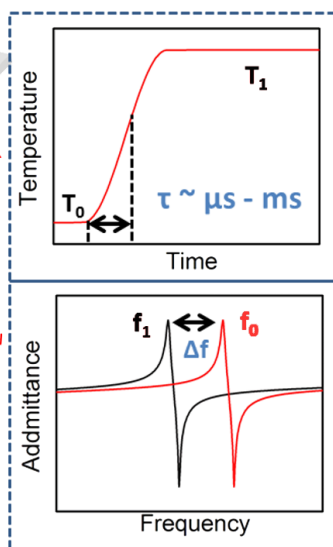
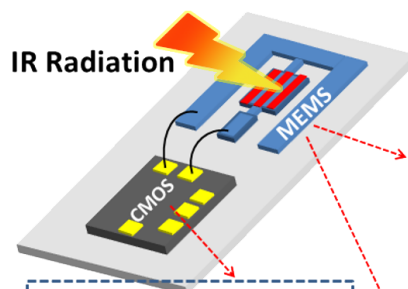
- High sensitivity to external perturbations
- High Q guarantees ultra-low noise
- Lithographically defined absorption band

# Piezoelectric Resonant Thermal Detector



$W_0$

$f_0 = \frac{1}{2W_0} \sqrt{\frac{E_{eq}}{\rho_{eq}}}$  **Temperature**



$$NEP = \frac{\Delta f_{noise}}{R_s}$$

$$\Delta f_{noise} = \sqrt{\frac{K_B T_0 (1 + F_c) B}{4 P_c}} \cdot \frac{f_0}{Q}$$

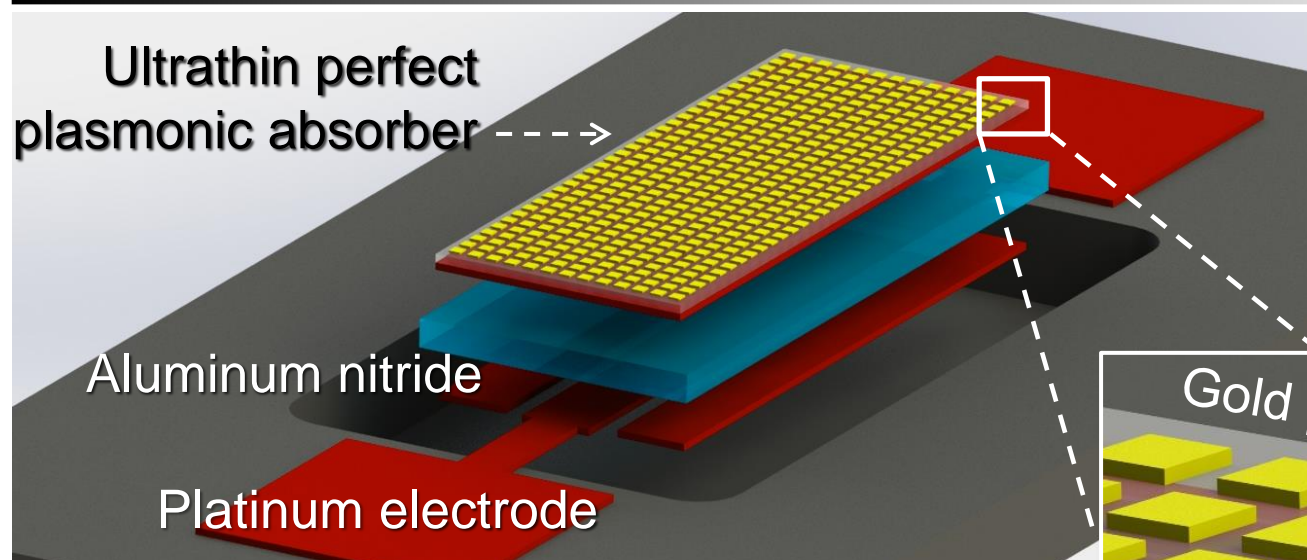
$$R_s = \frac{\Delta f_{IR}}{Q_p} = \eta \cdot R_{th} \cdot TCF \cdot f_0$$

$$\tau = R_{th} \cdot C_{th} \quad C_{th} \propto A \cdot t \quad C_0 \propto \frac{A}{t}$$

$$FoM = \frac{1}{NEP \cdot \tau} \propto \frac{\eta \cdot TCF \cdot Q}{C_0 \cdot t^2}$$



# Integration of ultrathin narrowband absorber

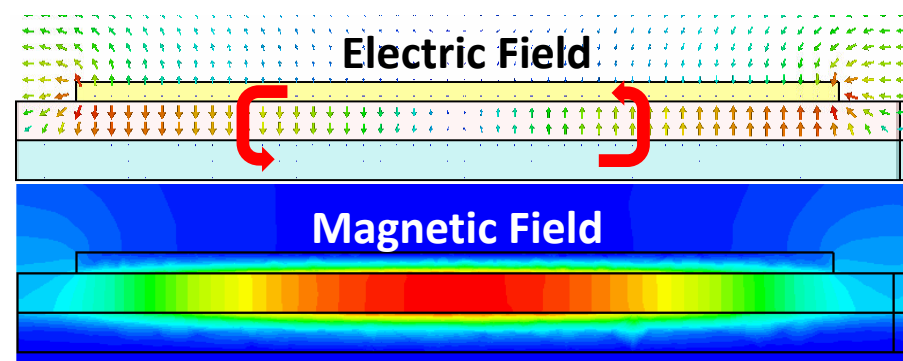
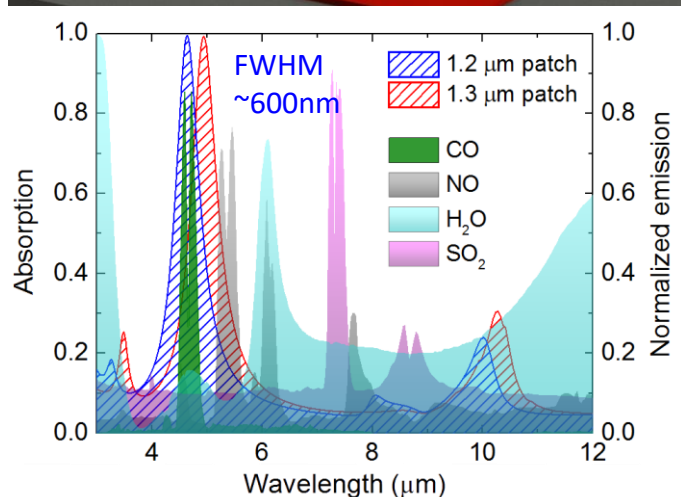
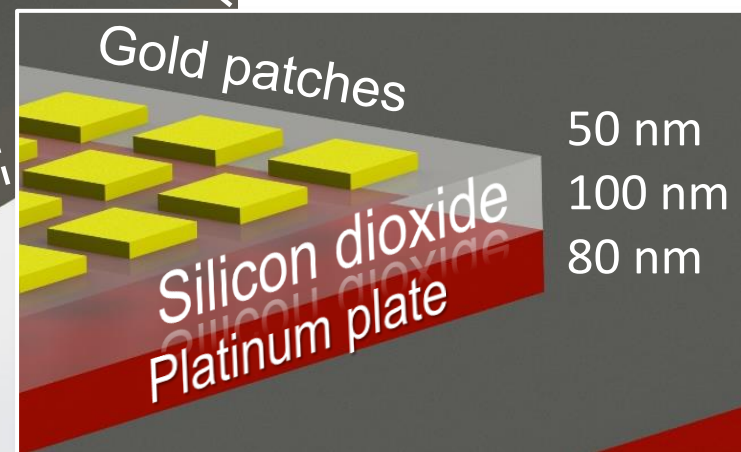


Full coverage of absorber

Near-unity absorption

FWHM  $\sim 10\%$

230 nm total thickness

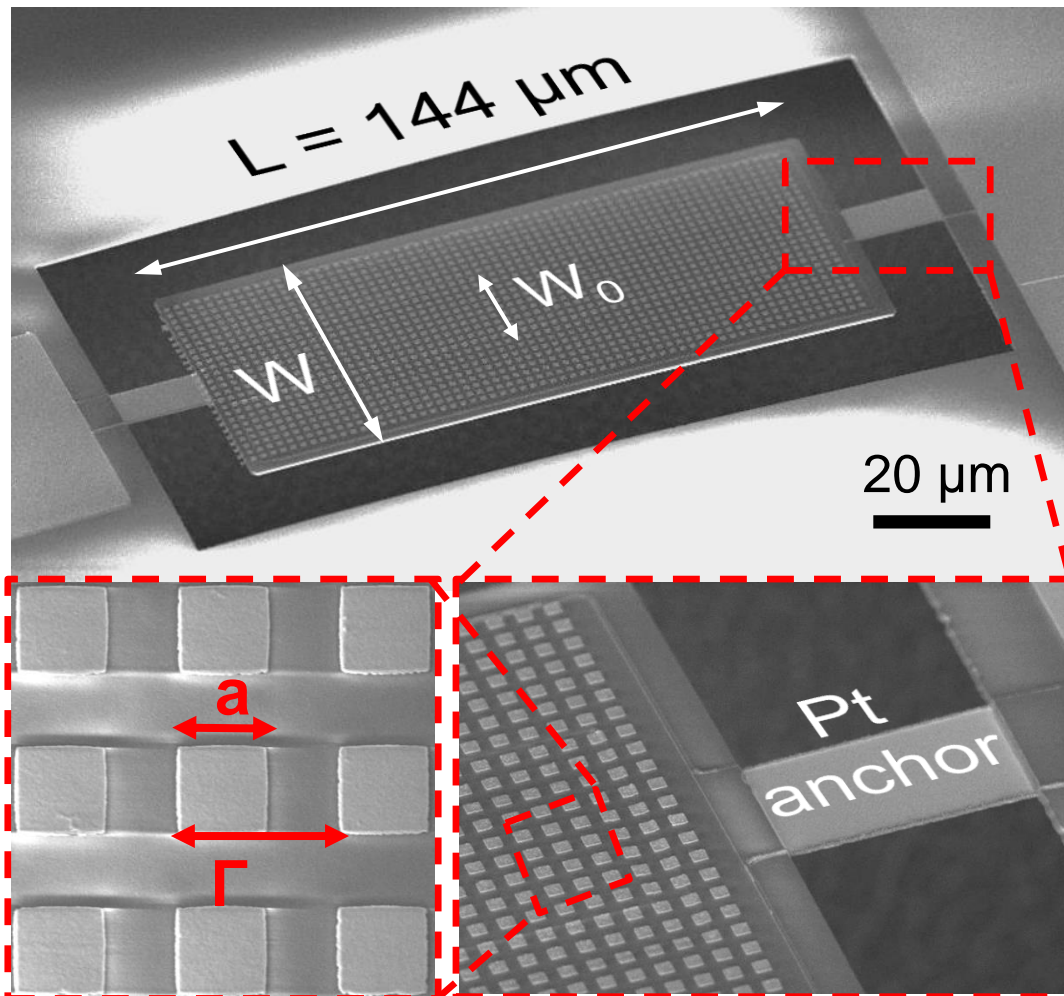
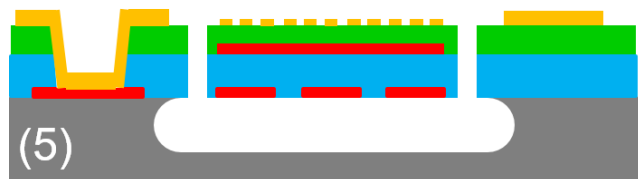
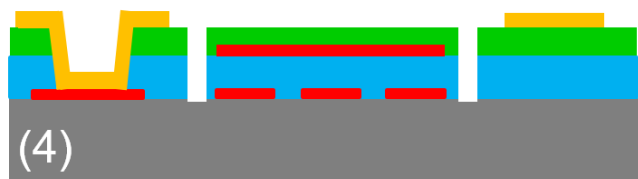


Z. Qian, S. Kang, V. Rajaram and M. Rinaldi; *Proceeding of the IEEE Sensors 2016 Conference (Sensors 2016)*, pp. 1-3, doi: 10.1109/ICSENS.2016.7808614



# Microfabrication

Si
  Pt
  AlN
  Au
  SiO<sub>2</sub>



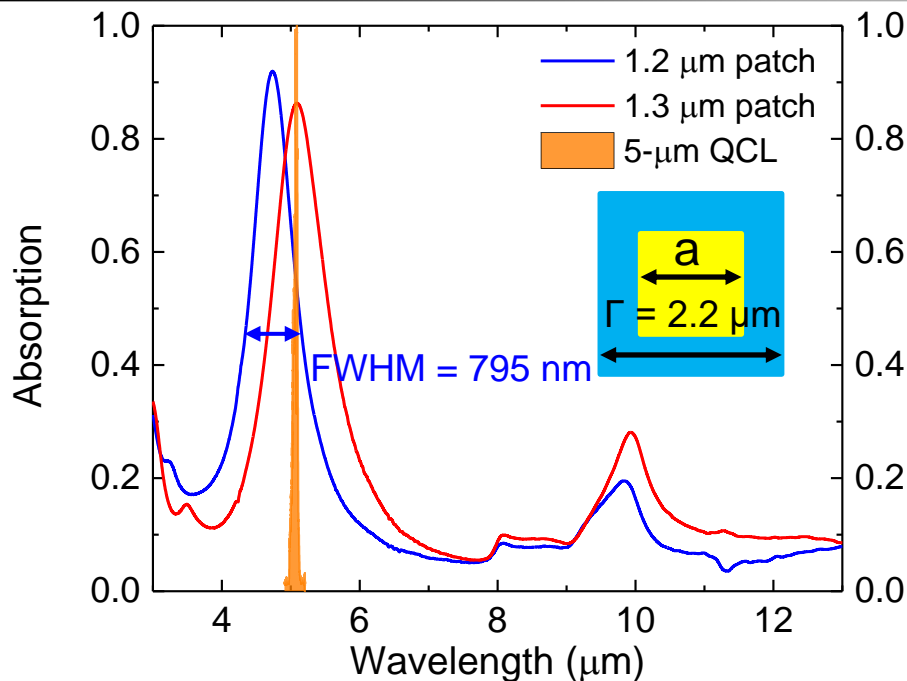
$a=1.2$  or  $1.3 \mu\text{m}$ ,  $\Gamma=2.2 \mu\text{m}$ ,  $W=60 \mu\text{m}$ ,  $W_0=20 \mu\text{m}$

Z. Qian, S. Kang, V. Rajaram and M. Rinaldi; *Proceeding of the IEEE Sensors 2016 Conference (Sensors 2016)*,

pp. 1-3, doi: 10.1109/ICSENS.2016.7808614

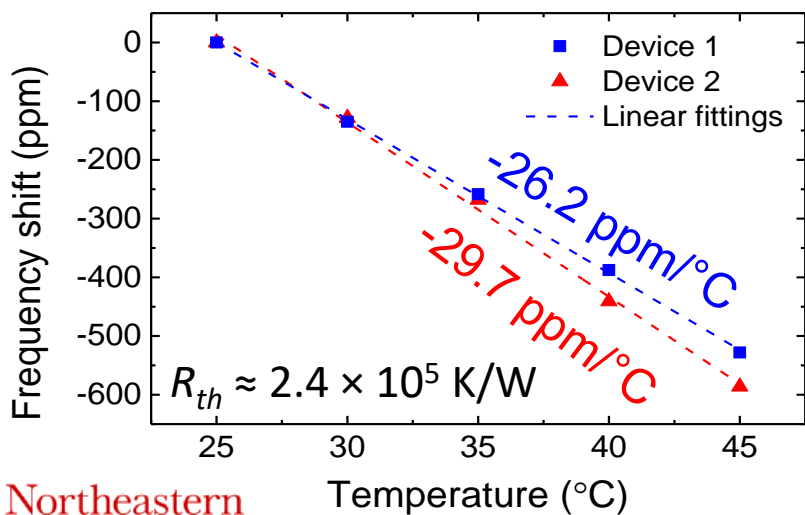


# Experimental results

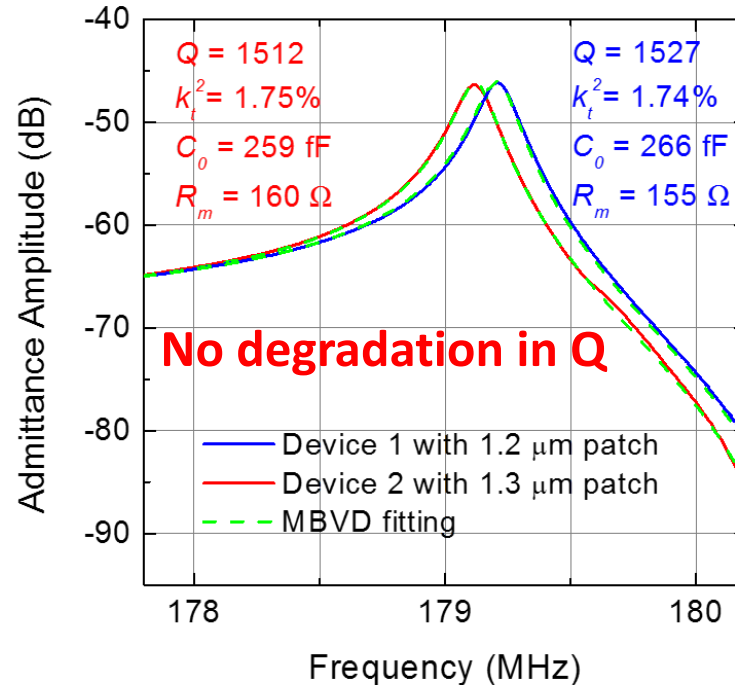


Normalized emission

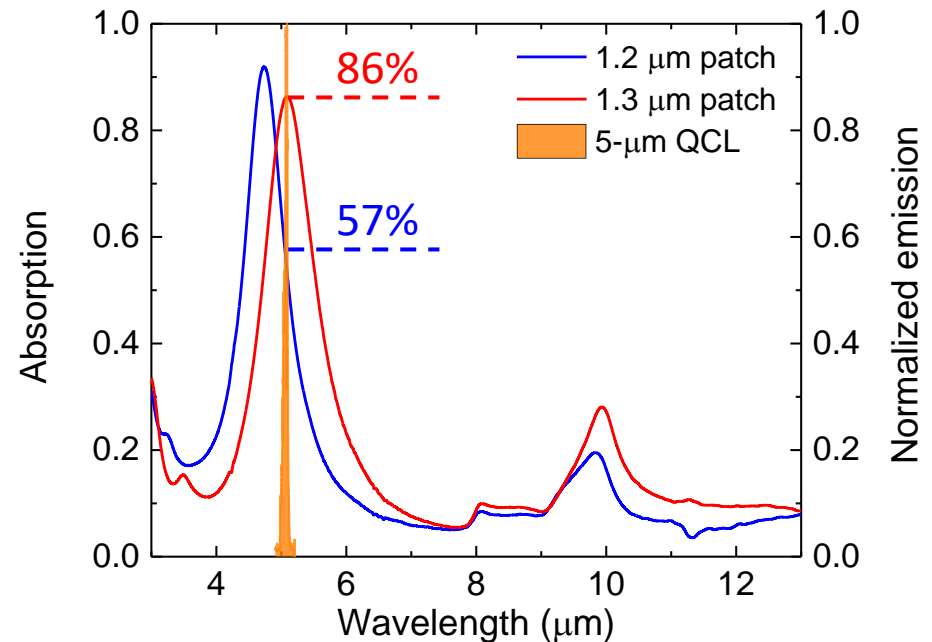
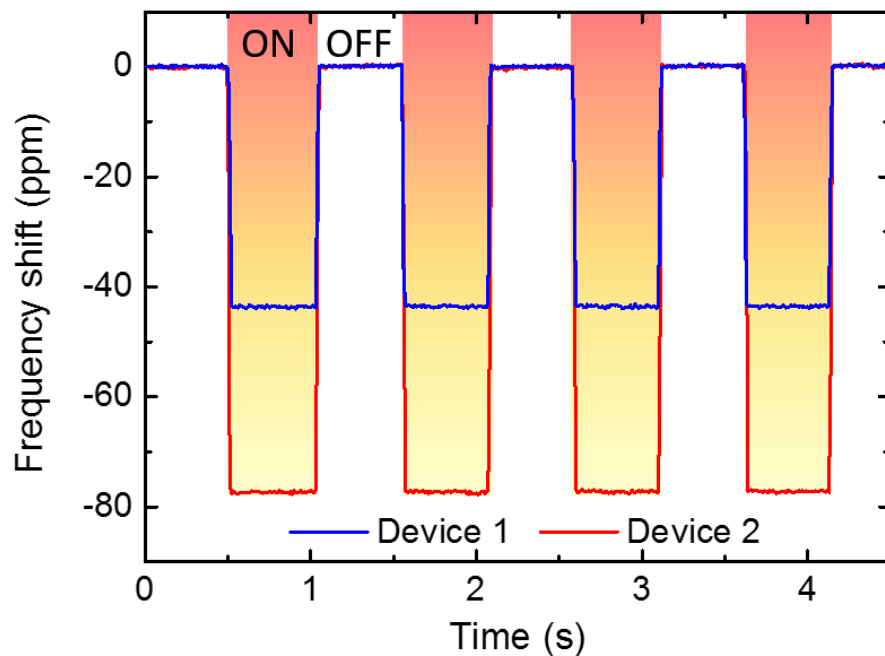
**Absorptance  $\sim 92\%$ , FWHM  $\sim 16\%$**



Z. Qian, S. Kang, V. Rajaram and M. Rinaldi; *Proceeding of the IEEE Sensors 2016 Conference (Sensors 2016)*, pp. 1-3, doi: 10.1109/ICSENS.2016.7808614



# Frequency response to IR radiation



$$R_{th} \approx 2.4 \times 10^5 \text{ K/W}$$

$$\tau \approx 3.5 \text{ ms}$$

$$\Delta f_{noise} \approx 3.7 \text{ ppb/Hz}^{1/2}$$

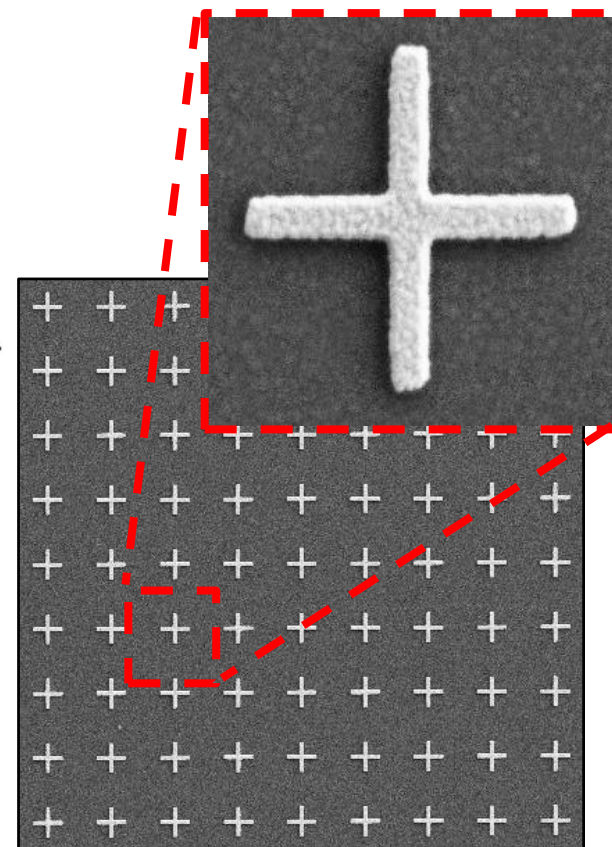
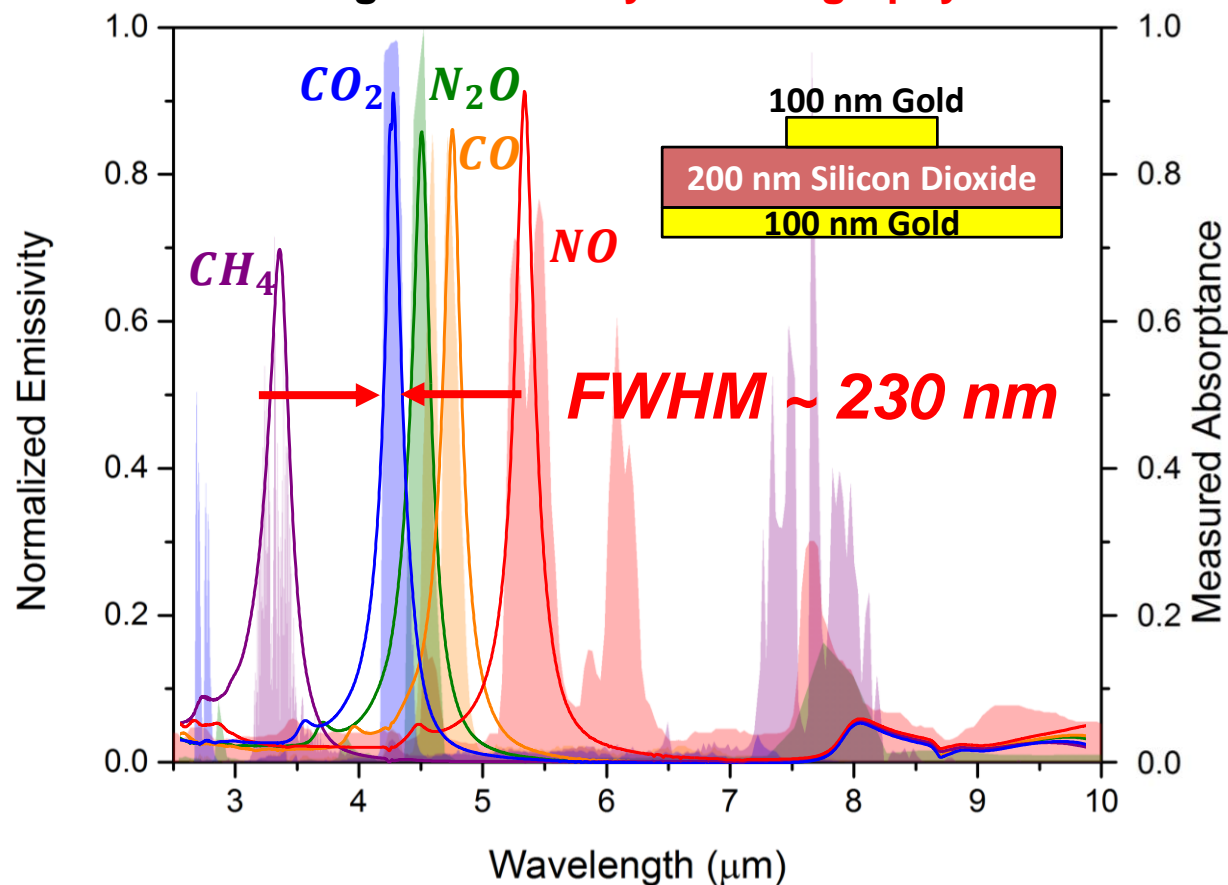
$$NEP \approx 633 \text{ pW/Hz}^{1/2} \text{ (at } 4.7 \text{ } \mu\text{m)}$$

Z. Qian, S. Kang, V. Rajaram and M. Rinaldi; *Proceeding of the IEEE Sensors 2016 Conference (Sensors 2016)*, pp. 1-3, doi: 10.1109/ICSENS.2016.7808614



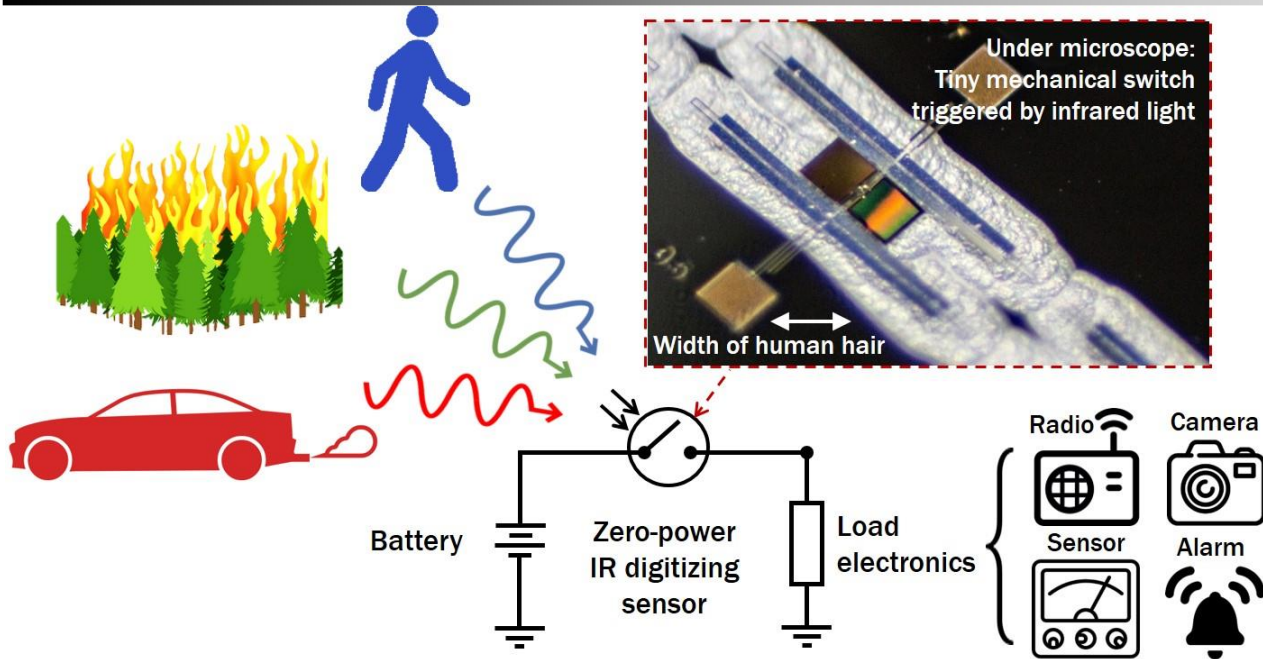
# Spectral Selectivity for Trace-Gas Emission

- Absorbers tuned to match **5 major trace-gas emission**
- FWHM < 5% allows a **superior selectivity** for closely-located IR signatures
- Peak wavelength tuned **only via lithography**



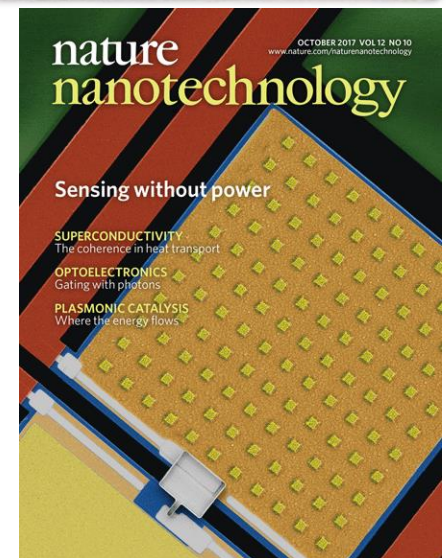
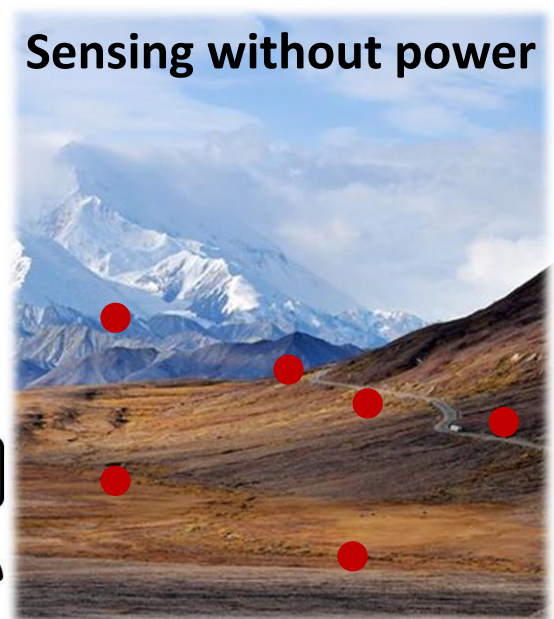
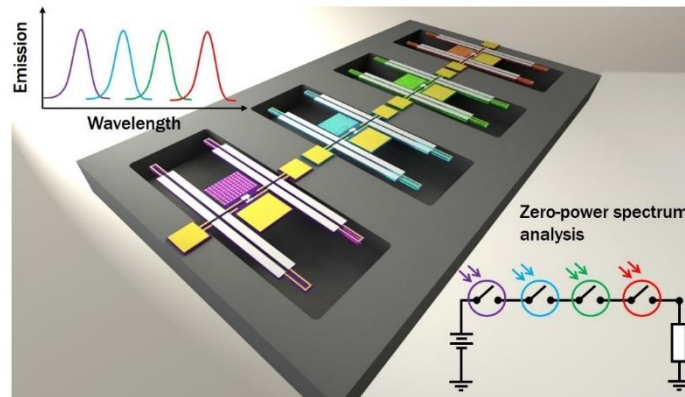
S. Kang, Z. Qian, V. Rajaram, A. Alu' and M. Rinaldi, *Proceedings of the 19th International Conference on Solid-State Sensors, Actuators and Microsystems (Transducers 2017)*, pp. 886-889. doi: 10.1109/TRANSDUCERS.2017.7994191.

# Zero-Power Infrared Digitizing Sensors



- A **passive microsystem** that combines **sensing, signal processing** and **comparator** functionalities.

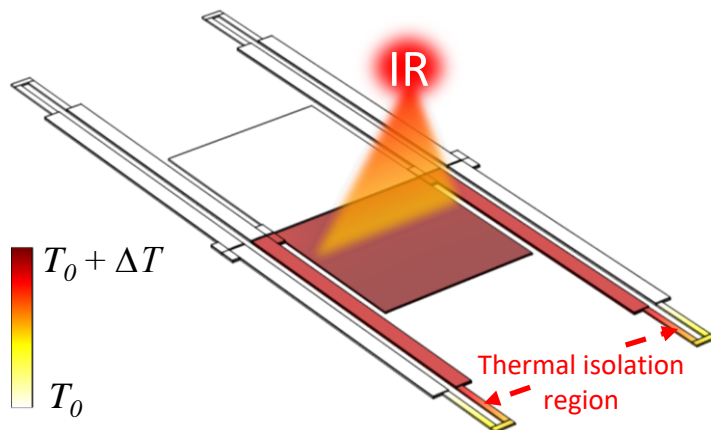
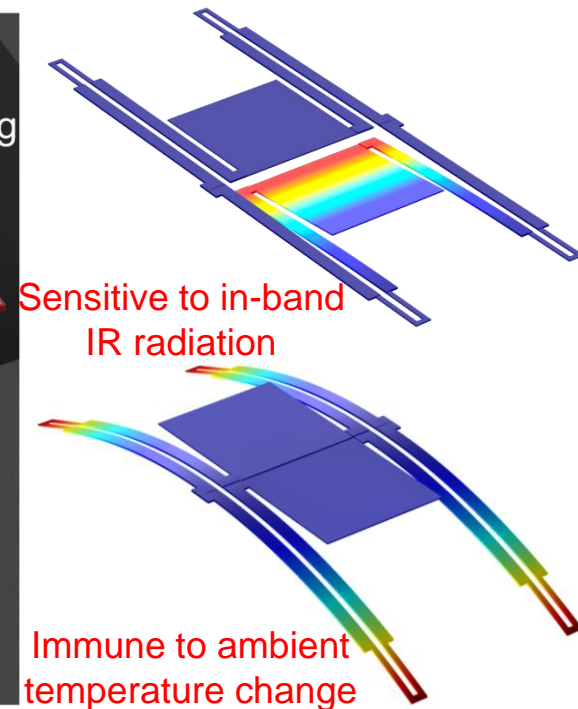
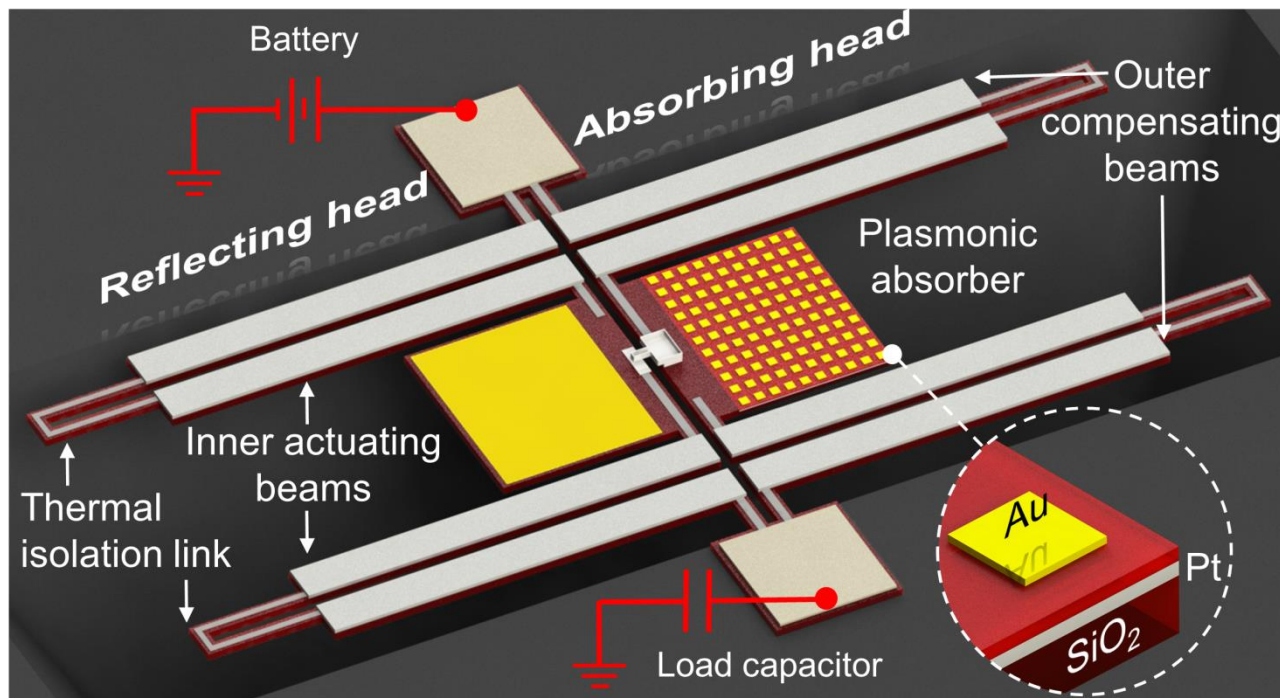
- The sensor produces a **digitized output bit** in the presence of the unique **IR spectral signatures**.



Z. Qian, S. Kang, V. Rajaram, C. Cassella, N. McGruer and M. Rinaldi, "Zero Power Infrared Digitizers Based on Plasmonically-enhanced Micromechanical Photoswitches", *Nature Nanotechnology*, 12, 969-973, doi:10.1038/nnano.2017.147



# Plasmonically-enhanced Micromechanical Photoswitch (PMP)



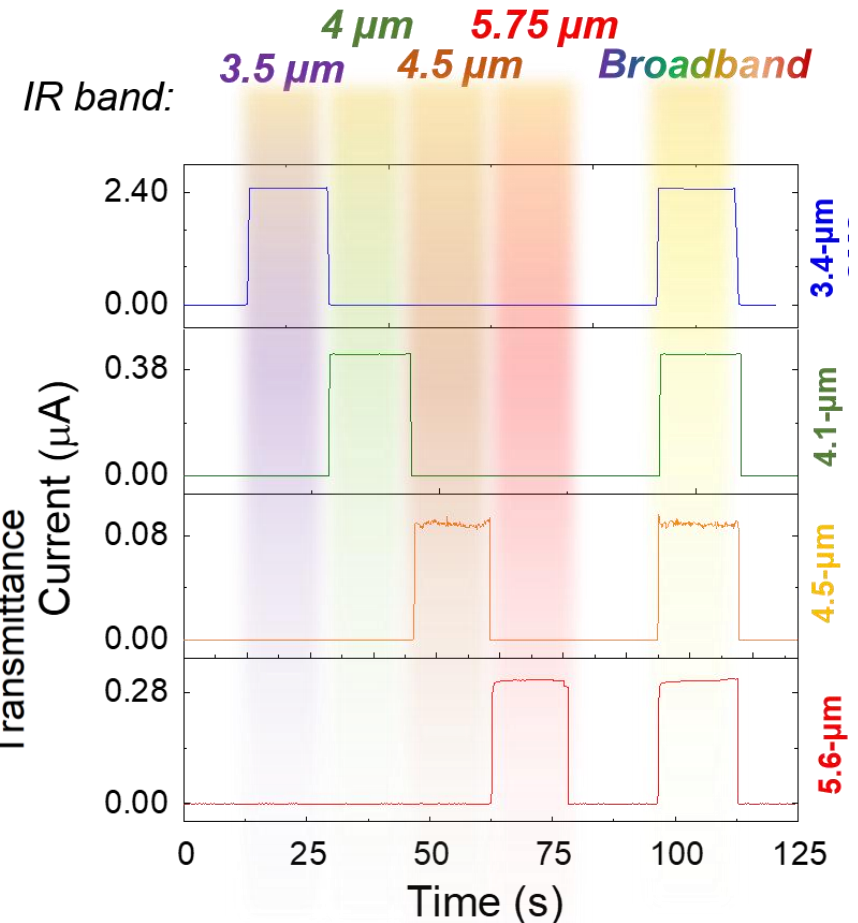
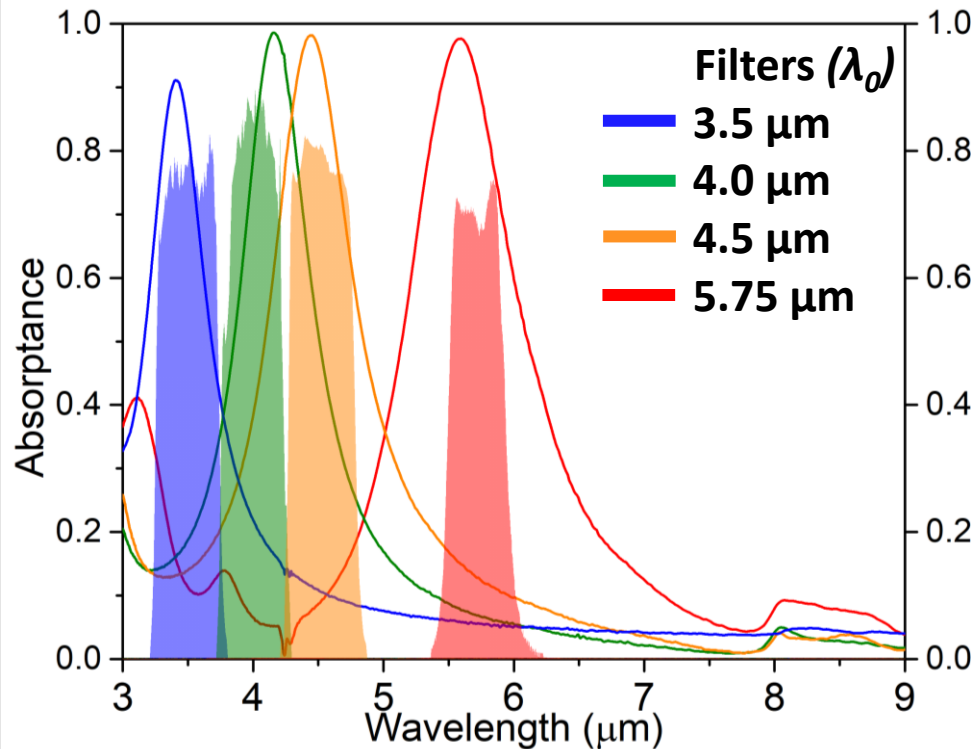
- Micromechanical switch selectively triggered by IR radiation at a specific spectral wavelength through a **plasmonically-enhanced thermomechanical coupling**
- **Immune to ambient temperature changes and residual stress**

Z. Qian, S. Kang, V. Rajaram, C. Cassella, N. McGruer and M. Rinaldi, "Zero Power Infrared Digitizers Based on Plasmonically-enhanced Micromechanical Photoswitches", *Nature Nanotechnology*, 12, 969-973, doi:10.1038/nnano.2017.147

# Spectral Selectivity

Device	Infrared Spectral State				
	3.5 $\mu\text{m}$ Band	4.0 $\mu\text{m}$ Band	4.5 $\mu\text{m}$ Band	5.75 $\mu\text{m}$ Band	Broad-band
3.4 $\mu\text{m}$ PMP	1	0	0	0	1
4.1 $\mu\text{m}$ PMP	0	1	0	0	1
4.5 $\mu\text{m}$ PMP	0	0	1	0	1
5.6 $\mu\text{m}$ PMP	0	0	0	1	1

- PMPs turn **ON** only at the specific IR band radiation with absorbed power > 500 nW, and remain OFF otherwise.



V. Rajaram, Z. Qian, S. Kang, C. Cassella, N. McGruer and M. Rinaldi, *Proceedings of the 19th International Conference on Solid-State Sensors, Actuators and Microsystems (Transducers 2017)*, pp. 846-849. doi: 10.1109/TRANSDUCERS.2017.7994181

# Acknowledgment

## Research Scientist:

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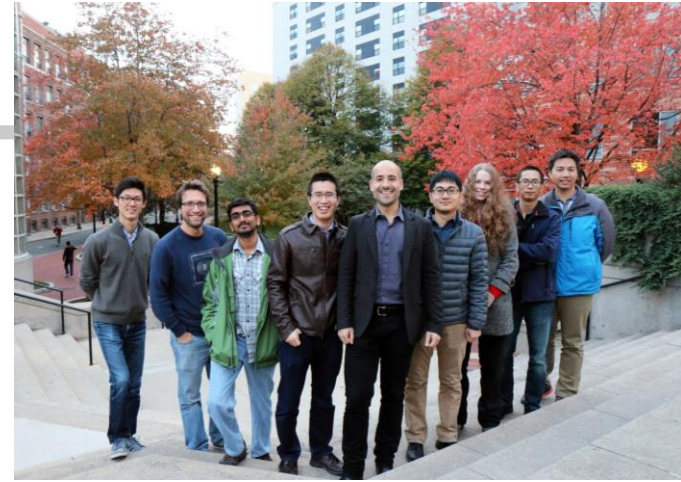
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- Prof. Andrea Alu'



### Young Faculty Award

N66001-12-1-4221

### DARPA RF-FPGA Program

N66001-14-1-4011

### DARPA NZero Program

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HR0011-15-C-0138

### DARPA SPAR Program

HR0011-17-2-0002



DHS Center of Excellence



### CAREER Award

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### NeTS Small

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